BUX85

SWITCHMODE™ NPN Silicon Power Transistors

The BUX85 is designed for high voltage, high speed power switching applications like converters, inverters, switching regulators, motor control systems.

Features

- $V_{CEO(sus)}$ − 450 V
- $V_{CES(sus)}$ − 1000 V
- Fall time = 0.3 μs (typ) at I_C = 1.0 A
- $V_{CE(sat)}$ = 1.0 V (max) at I_C = 1.0 A, I_B = 0.2 A
- Pb−Free Package is Available*

ON Semiconductor®

2.0 AMPERES
POWER TRANSISTOR
NPN SILICON
450 VOLTS, 50 WATTS

TO−220AB
CASE 221A−09
STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector−Emitter Voltage	$V_{CEO(sus)}$	450	Vdc
Collector−Emitter Voltage	V_{CES}	1000	Vdc
Emitter−Base Voltage	V_{EBO}	5	Vdc
Collector Current – Continuous – Peak (Note 1)	I_C I_{CM}	2 3.0	Adc
Base Current – Continuous – Peak (Note 1)	I_B I_{BM}	0.75 1.0	Adc
Reverse Base Current – Peak	I_{BM}	1	Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	50 400	W W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−65 to +150	°C

THERMAL CHARACTERISTICS

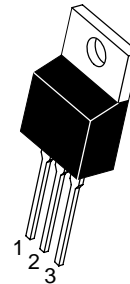| Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8″ from Case for 5 Seconds	T_L	275	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.
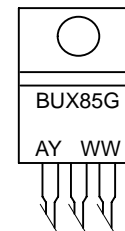1. Pulse Test: Pulse Width = 5 ms, Duty Cycle ≦ 10%.

MARKING DIAGRAM

BUX85G
AY WW

BUX85	= Device Code
A	= Assembly Location
Y	= Year
WW	= Work Week
G	= Pb−Free Package

ORDERING INFORMATION

Device	Package	Shipping
BUX85	TO−220	50 Units / Rail
BUX85G	TO−220 (Pb−Free)	50 Units / Rail

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BUX85

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS (Note 2)					
Collector−Emitter Sustaining Voltage (I_C = 100 mAdc, (L = 25 mH) See Figure 1	$V_{CEO(sus)}$	450	–	–	Vdc

Collector Cutoff Current
  (V_{CES} = Rated Value)
  (V_{CES} = Rated Value, T_C = 125°C)
	I_{CES}	
		–
		–
			
			–
			–
				
				0.2
				1.5
					mAdc

Emitter Cutoff Current (V_{EB} = 5 Vdc, I_C = 0)	I_{EBO}	–	–	1	mAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain (I_C = 0.1 Adc, V_{CE} = 5 V)	h_{FE}	30	50	–	–

Collector−Emitter Saturation Voltage
  (I_C = 0.3 Adc, I_B = 30 mAdc)
  (I_C = 1 Adc, I_B = 200 mAdc)
	$V_{CE(sat)}$	
		–
		–
			
			–
			–
				
				0.8
				1
					Vdc

Base−Emitter Saturation Voltage (I_C = 1 Adc, I_B = 0.2 Adc)	$V_{BE(sat)}$	–	–	1.1	Vdc
DYNAMIC CHARACTERISTICS					
Current−Gain − Bandwidth Product (I_C = 500 mAdc, V_{CE} = 1 0 Vdc, f = 1 MHz)	f_T	4	–	–	MHz

SWITCHING CHARACTERISTICS

		Symbol	Min	Typ	Max	Unit
Turn−on Time	V_{CC} = 250 Vdc, I_C = 1 A I_{B1} = 0.2 A, I_{B2} = 0.4 A See Figure 2	t_{on}	–	0.3	0.5	μs
Storage Time		t_s	–	2	3.5	μs
Fall Time		t_f	–	0.3	–	μs
Fall Time	Same above cond. at T_C = 95°C	t_f	–	–	1.4	μs

2. Pulse Test: PW = 300 μs, Duty Cycle ≦ 2%.

BUX85

PACKAGE DIMENSIONS

TO–220AB
CASE 221A–09
ISSUE AA
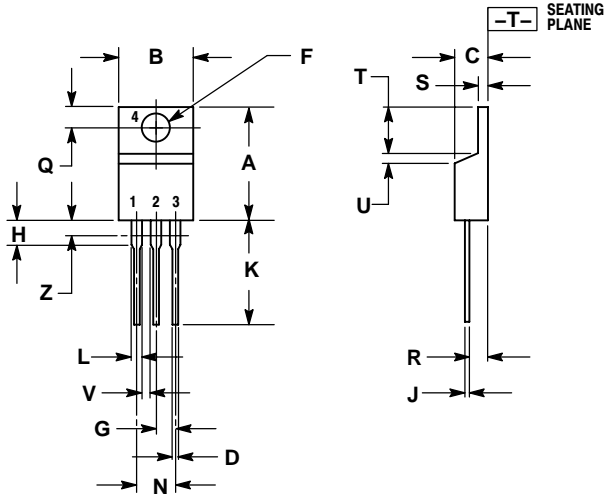
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

SEATING PLANE −T−

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR